

Research paper

Contents lists available at [ScienceDirect](www.sciencedirect.com/science/journal/00092614)

Chemical Physics Letters

journal homepage: www.elsevier.com/locate/cplett

Facile synthesis of NiO nanoflakes via hydrothermal route: Effect of urea concentration

D.P. Mali ^a, R.T. Patil ^a, A.S. Patil ^b, V.J. Fulari ^{a,*}

^a *Holography and Materials Research Laboratory, Department of Physics, Shivaji University, Kolhapur 416004, M.H., India* ^b *Rajarshi Chhatrapati Shahu College, Kolhapur, M.H., India*

1. Introduction

Recently, population growth and depletion of natural resources have contributed to the energy crisis as a modern global issue [1]. As a result of these issues, researchers are interested in researching various forms of energy storage devices such as batteries, supercapacitors, condensers, etc. Due to its high quality of power density, energy density, and long cycle lifespan [2,3], the supercapacitor made up of electrochemical reaction is one of the excellent electric energy storage device.

There are three types of supercapacitors such as pseudocapacitors (PCs), electrochemical double-layer condensers (EDLCs), and hybrid superconductors $[4]$. In the case of pseudocapacitors, the faradic electron charge-transfer takes place with the redox reaction while in EDLCs, electric double layers are formed at the boundary of the electrodeelectrolytic solution. Mostly, conducting polymers, various metal oxides, and composite materials are mainly used as pseudocapacitors [5].

These pseudocapacitor materials are being mostly utilized in supercapacitors than EDLCs. It is well known that $RuO₂$ has a high theoretical specific capacitance of 1400-2000 Fg^{-1} [6] and is one of the best supercapacitor material. But because of its rarity, high cost, it is a very difficult job to utilize it on a commercial scale. Researchers are therefore trying to substitute inexpensive earth-abundant and suitable metal oxides such as $MnO₂$, Fe₂O₃, NiO, Co₃O₄, etc.

Among these materials, NiO is a flexible low cast transition metal oxide with good pseudocapacitive behavior. Nickel Oxide is a semiconductor possessing holes as majority charge carriers. The energy band gap of NiO is lying in the ranges of 3.6–4.0 eV [7]. Such outstanding features showing NiO material have a plethora of applications such as transparent electrodes in display and photovoltaic devices [8], photocatalysis [9], dye-sensitized solar cells [10], electrochromic devices [11], chemical sensors [12] and supercapacitors [13]. For the synthesis of a nickel oxide material various techniques were used like are spray pyrolysis [14], electrodeposition [15], chemical bath deposition [16], and SILAR [17], hydrothermal method [18,19], etc.

A hydrothermal method is cost-effective among these various methods easily carried out under controlled conditions above the room temperature to obtain NiO with precise morphology. The size, growth, and morphology of electrode material are very easy to control in hydrothermal route by changing the different parameters such as time of reaction, temperature retention, and precursor concentration of the reactants. The pH of growth solution was controlled by the concentration of the reactant [20]. By choosing suitable precipitants such as urea, oxalic acid, ammonium hydroxide, ammonium carbonate, and others the pH of growth solution can be easily controlled in hydrothermal route. [21].

Various morphologies of the NiO films such as nanofiber [22], flowerlike [23], nanocubes [24], nanospheres [25], nanowires [26], nanoflakes [27], etc have been obtained. It is well recognized that NiO's physicochemical properties are of highly depend on structure, morphology, and size. Therefore from the point of researcher's view the preparation of porous materials with various morphologies and hierarchical structures is illustrated. NiO nanoflowers showing 47.6 Fg-

<https://doi.org/10.1016/j.cplett.2021.138431>

Available online 11 February 2021 0009-2614/© 2021 Published by Elsevier B.V. Received 10 November 2020; Received in revised form 20 January 2021; Accepted 7 February 2021

^{*} Corresponding author. *E-mail address:* vijayfulari@gmail.com (V.J. Fulari).